BLS6G3135-20; BLS6G3135S-20 LDMOS S-Band radar power transistor

AMPLEON

Rev. 5 — 1 September 2015

Product data sheet

Product profile 1.

1.1 General description

20 W LDMOS power transistor intended for radar applications in the 3.1 GHz to 3.5 GHz range.

Table 1. **Typical performance**

Typical RF performance at $T_{case} = 25$ °C; $t_{p} = 300 \ \mu s$; $\delta = 10$ %; $I_{Dq} = 50 \ mA$; in a class-AB production test circuit.

Mode of operation	f	V _{DS}	PL	Gp	η _D	t _r	t _f
	(GHz)	(V)	(W)	(dB)	(%)	(ns)	(ns)
Pulsed RF	3.1 to 3.5	32	20	15.5	45	20	10

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

1.2 Features and benefits

- Typical pulsed RF performance at a frequency of 3.1 GHz to 3.5 GHz, a supply voltage of 32 V, an I_{Dq} of 50 mA, a t_p of 300 μs and a δ of 10 %:
 - ◆ Output power = 20 W
 - ◆ Power gain = 15.5 dB
 - ◆ Efficiency = 45 %
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (3.1 GHz to 3.5 GHz)
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

■ S-Band power amplifiers for radar applications in the 3.1 GHz to 3.5 GHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
BLS6G313	35-20 (SOT608A)		
1	drain		,
2	gate		1
3	source		2 3
BLS6G313	35S-20 (SOT608B)		sym112
1	drain		4
2	gate		با
3	source	[1]	2 3 sym112

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLS6G3135-20	-	flanged ceramic package; 2 mounting holes; 2 leads	SOT608A
BLS6G3135S-20	-	ceramic earless flanged package; 2 leads	SOT608B

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	60	V
V_{GS}	gate-source voltage		-0.5	+13	V
I _D	drain current		-	2.1	Α
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	225	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Max	Unit
$R_{\text{th(j-case)}}$ thermal resistance from junction to case	T_{case} = 80 °C; P_L = 20 W				
	t_p = 100 μ s; δ = 20 %	0.76	0.92	K/W	
		t_p = 300 μ s; δ = 10 %	0.79	0.95	K/W

6. Characteristics

Table 6. Characteristics

 $T_i = 25 \, ^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.5 \text{ mA}$	60	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 40 mA	1.4	2	2.4	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	1.5	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	6	8.2	-	Α
I _{GSS}	gate leakage current	$V_{GS} = 8.3 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	150	nA
9 _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 1.4 A	-	2.8	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 1.4 \text{ A}$	-	0.37	0.58	Ω

7. Application information

Table 7. Application information

Mode of operation: pulsed RF; $t_p = 300~\mu s$; $\delta = 10~\%$; RF performance at $V_{DS} = 32~V$; $I_{Dq} = 50~mA$; $T_{case} = 25~C$; unless otherwise specified; in a class-AB production circuit.

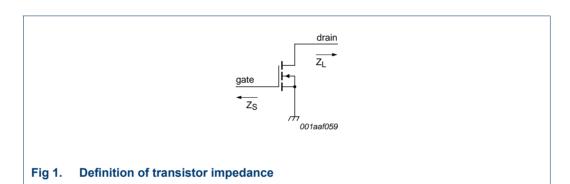
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
PL	output power		-	20	-	W
V _{CC}	supply voltage	P _L = 20 W	-	-	32	V
Gp	power gain	P _L = 20 W	12	15.5	-	dB
η_{D}	drain efficiency	P _L = 20 W	40	45	-	%
t _r	rise time	P _L = 20 W	-	20	50	ns
t _f	fall time	P _L = 20 W	-	10	50	ns

7.1 Impedance information

Table 8. Typical impedance

f	Z _S	Z_L (optimized for η_D)	Z _L (optimized for G _p)	G _{p(opt)}	η _D [1]
GHz	Ω	Ω	Ω	dB	%
3.1	31.24 – j31.07	6.99 + j12.9	13.01 + j14.75	18.08	48.34
3.2	50.56 - j12.48	5.82 + j8.77	11.47 + j11.17	17.97	45.60
3.3	43.66 + j17.27	2.32 + j6.17	10.05 + j10.55	17.75	47.01
3.4	24.13 + j28.47	5.52 + j6.10	9.93 + j8.48	17.91	47.03
3.5	10.56 + j22.21	5.79 + j3.19	9.37 + j5.73	17.68	46.54

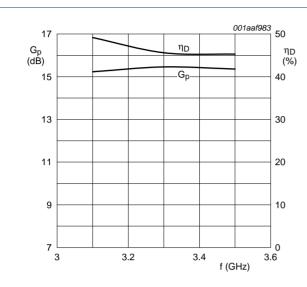
[1] Measured with Z_L optimized for G_p .



7.2 Ruggedness in class-AB operation

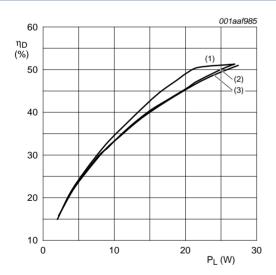
The BLS6G3135-20 and BLS6G3135S-20 are capable of withstanding a load mismatch corresponding to VSWR = 5 : 1 through all phases under the following conditions: V_{DS} = 32 V; I_{Dq} = 50 mA; P_{L} = 20 W; t_{p} = 300 μ s; δ = 10 %.

7.3 Graphs



 V_{DS} = 32 V; I_{Dq} = 50 mA; t_p = 300 $\mu s; \, \delta$ = 10 %; P_I = 20 W.

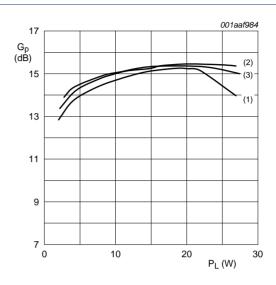




 V_{DS} = 32 V; I_{Dq} = 50 mA; t_p = 300 μ s; δ = 10 %.

- (1) f = 3.1 GHz
- (2) f = 3.3 GHz
- (3) f = 3.5 GHz

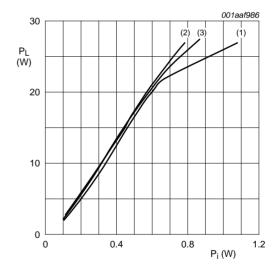
Fig 4. Efficiency as a function of load power; typical values



 V_{DS} = 32 V; I_{Dq} = 50 mA; t_p = 300 μ s; δ = 10 %.

- (1) f = 3.1 GHz
- (2) f = 3.3 GHz
- (3) f = 3.5 GHz

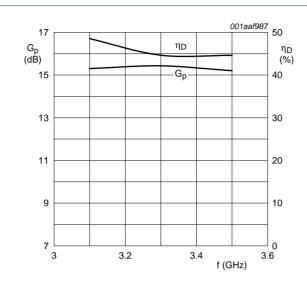
Fig 3. Power gain as a function of load power; typical values



 V_{DS} = 32 V; I_{Dq} = 50 mA; t_p = 300 μ s; δ = 10 %.

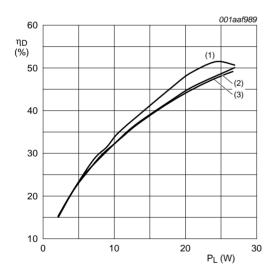
- (1) f = 3.1 GHz
- (2) f = 3.3 GHz
- (3) f = 3.5 GHz

Fig 5. Load power as a function of input power; typical values



 V_{DS} = 32 V; I_{Dq} = 100 mA; t_p = 50 $\mu s;$ δ = 20 %; P_L = 20 W.

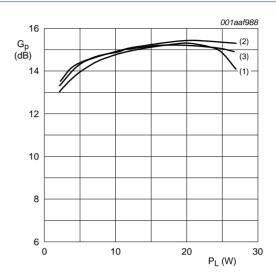




 V_{DS} = 32 V; I_{Dq} = 50 mA; t_p = 100 μ s; δ = 20 %.

- (1) f = 3.1 GHz
- (2) f = 3.3 GHz
- (3) f = 3.5 GHz

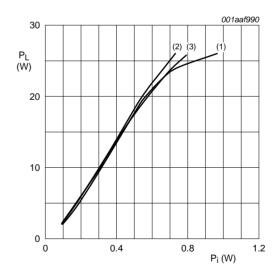
Fig 8. Efficiency as a function of load power; typical values



 V_{DS} = 32 V; I_{Dq} = 50 mA; t_p = 100 μ s; δ = 20 %.

- (1) f = 3.1 GHz
- (2) f = 3.3 GHz
- (3) f = 3.5 GHz

Fig 7. Power gain as a function of load power; typical values

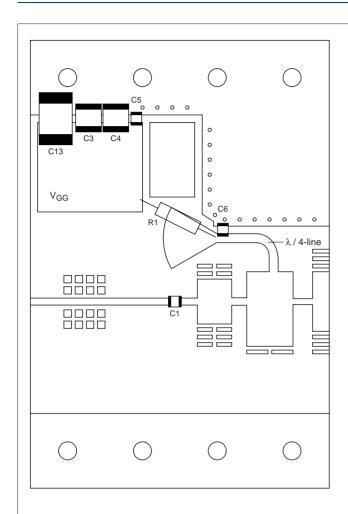


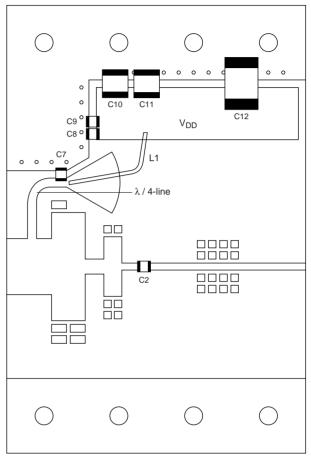
 V_{DS} = 32 V; I_{Dq} = 50 mA; t_p = 100 μ s; δ = 20 %.

- (1) f = 3.1 GHz
- (2) f = 3.3 GHz
- (3) f = 3.5 GHz

Fig 9. Load power as a function of input power; typical values

8. Test information





001aah590

Striplines are on a double copper-clad Rogers Duroid 6006 Printed-Circuit Board (PCB) with ε_r = 6.2 and thickness = 0.64 mm. See Table 9 for list of components.

Fig 10. Component layout for 3.1 GHz to 3.5 GHz test circuit

Table 9. List of components

See Figure 10.

Component	Description	Value	Remarks
C1, C2, C5, C6, C7, C8, C9	multilayer ceramic chip capacitor	33 pF	[1]
C3, C4, C10, C11	multilayer ceramic chip capacitor	470 pF	[2]
C12	electrolytic capacitor	47 μF; 63 V	
C13	electrolytic capacitor	10 μF; 35 V	
L1	copper wire	-	
R1	resistor	49.9 Ω	

- [1] American Technical Ceramics type 100A or capacitor of same quality.
- [2] American Technical Ceramics type 100B or capacitor of same quality.

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9. Package outline

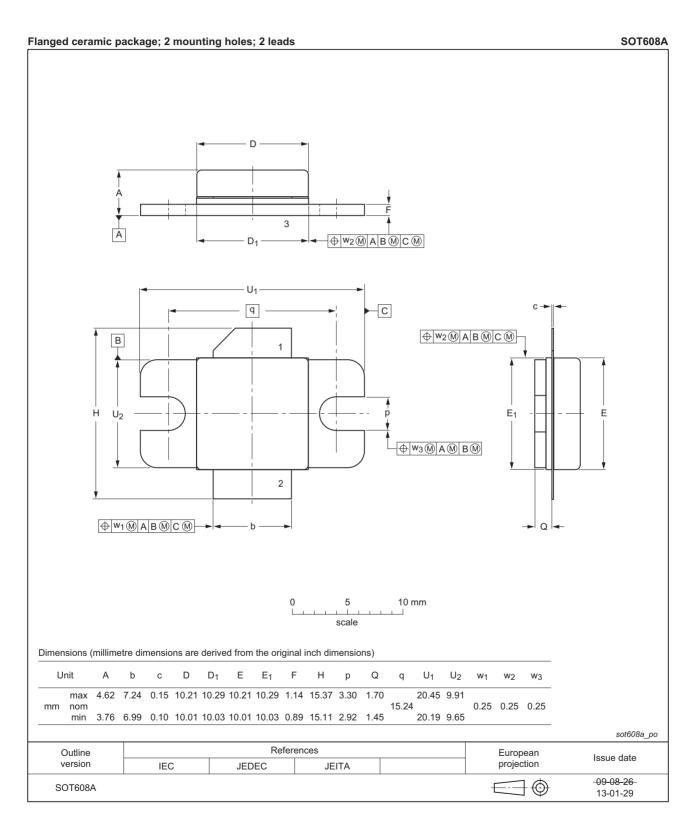


Fig 11. Package outline SOT608A

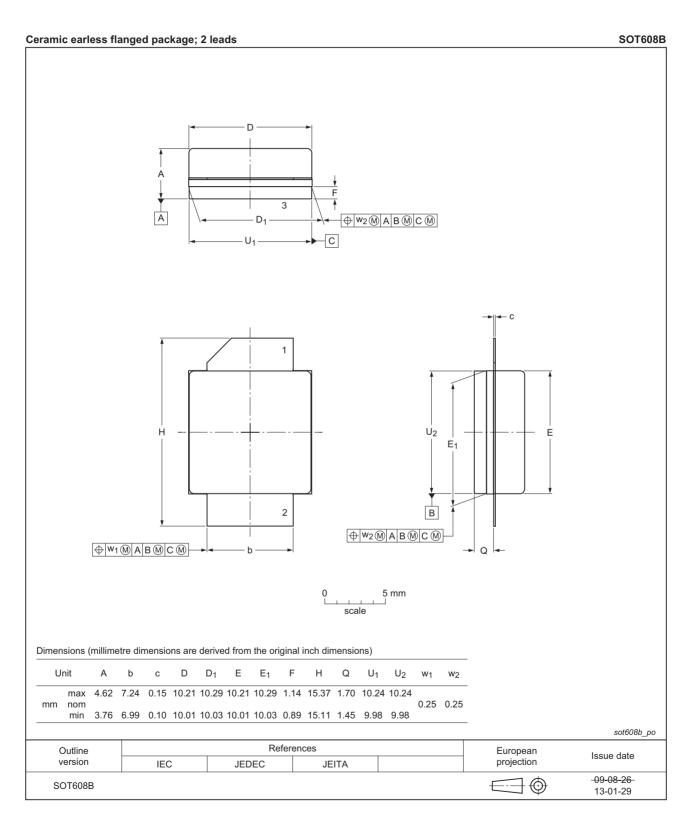


Fig 12. Package outline SOT608B

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
LDMOS	Laterally Diffused Metal Oxide Semiconductor
RF	Radio Frequency
S-Band	Short wave Band
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLS6G3135-20_6G3135S-20#5	20150901	Product data sheet		BLS6G3135-20_6G3135S-20_4
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. 			
	 Legal texts 	s have been adapted to	the new compar	ny name where appropriate.
BLS6G3135-20_6G3135S-20_4	20130311	Product data sheet	-	BLS6G3135-20_6G3135S-20_3
BLS6G3135-20_6G3135S-20_3	20090303	Product data sheet	-	BLS6G3135-20_6G3135S-20_2
BLS6G3135-20_6G3135S-20_2	20081217	Product data sheet	-	BLS6G3135-20_6G3135S-20_1
BLS6G3135-20_6G3135S-20_1	20070307	Objective data sheet	-	-

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14. Contents

1	Product profile
1.1	General description
1.2	Features and benefits
1.3	Applications
2	Pinning information
3	Ordering information
4	Limiting values
5	Thermal characteristics
6	Characteristics
7	Application information
7.1	Impedance information
7.2	Ruggedness in class-AB operation
7.3	Graphs
8	Test information
9	Package outline
10	Abbreviations
11	Revision history
12	Legal information
12.1	Data sheet status 1
12.2	Definitions
12.3	Disclaimers 1
12.4	Trademarks12
13	Contact information
1/	Contents 11

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